Sythesis and Characterization of CIGS nano-particles by Wet Process

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In this study, CIGS nanoparticles were synthesized by colloidal route. Cupric chloride (CuCl), Indium trichloride (InCl3), Gallium trichloride (GaCl3) were dissolved in ethyl alcohol (C2H5OH), and Selenium (Se) was dissolved in ethylenediamine (C2H8N2) respectively. As-synthesized nanoparticles were washed with methyl alcohol to remove impurities and dried to obtain pure CIGS nanoparticles in a vacuum oven. As-synthesized CIGS nanoparticles were dispersed in Isobuthyl alcohol (C4H9OH) to obtain a nanoparticles ink. Deposited thin films annealing temperature were up to 550 °C at N2 atmosphere for 2 hrs. The properties of CIGS nanoparticles ink were investigated by SEM, XRD, TEM and PL. We found that the growth temperature and Cu/(In + Ga) ratio are important factors in controlling the nanoparticles.

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